



# ML22420MB/ML22460MB

Speech Synthesis LSI with Serial ROM Interface Including 4-Channel Mixing Function

### **GENERAL DESCRIPTION**

ML22420 and ML22460 are voice synthesis LSIs with serial interface to the external ROM that stores voice data.

These LSIs include edit ROM, ADPCM2 decoder, 16-bit DA converter, low pass filter and monaural speaker amplifier. Also, ML22420 supports the synchronous serial interface and ML22460 supports the I2C interface. By integrating all the functions required for voice output into a single chip, these LSIs can be more easily incorporated in compact portable devices.

- Maximum External ROM capacity: 128Mbits
- External ROM capacity and maximum vocal reproduction time:

(at the case of 4-bit OKI ADPCM2 algorithm)							
External	Maximum vocal reproduction time (sec)						
ROM capacity	F <sub>S</sub> = 4.0 kHz	F <sub>S</sub> = 8.0 kHz	F <sub>S</sub> = 16 kHz				
128 Mbits	8,352	4,176	2,088				
64 Mbits	4,176	2,088	1,044				
16 Mbits	1,044	522	261				

• Voice synthesis method:	4-bit OKI ADPCM2
	8-bit Nonlinear PCM
	8-bit PCM, 16-bit PCM
	Can be specified for each phrase.
• Sampling frequency(F <sub>s</sub> ):	4.0 / 5.3 / 6.4 / 8.0 / 10.6 / 12.0 / 12.8 / 16.0 / 21.3 / 24.0 / 25.6 / 32.0 /
	48.0 kHz
	F <sub>s</sub> can be specified for each phrase.
• Built-in low-pass filter and 16-bit DA	A converter
<ul> <li>Speaker driving amplifier:</li> </ul>	$0.7 \text{ W}$ (when Z=8 $\Omega$ , DV <sub>DD</sub> =5 V, Ta=25°C)
	2ch analog inputs (internal: 1ch, external: 1ch)
• CPU command interface:	3-wired serial clock-synchronized (ML22420)
	I2C interface (ML22460)
• Maximum number of phrases:	1024 phrases from 000h to 3FFh
• Volume control:	32 levels (OFF is included) can be set by CVOL command.
	50 levels (OFF is included) can be set by AVOL command.
• Repeat function:	LOOP commands
• 4-channel mixing function:	Available when F <sub>s</sub> for each channel is 16kHz or less
<ul> <li>Master clock frequency:</li> </ul>	4.096 MHz
• Power supply voltage:	2.7 V to 5.5 V
• Operating temperature range:	$-40^{\circ}$ C to $+85^{\circ}$ C
Package:	30-pins plastic SSOP (SSOP30-P-56-0.65-K-MC)
Product name:	ML22420, ML22460

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Item	MSM9841	ML2240	ML22420/460
CPU interface	Parallel	Parallel/Serial	Serial/I2C
Voice memory	external	$\leftarrow$	$\leftarrow$
Memory interface	8/16-bits parallel	8-bits parallel	Serial
Voice synthesis algorithm	4-bit Oki ADPCM2 8-bit nonlinear PCM 8-bit straight PCM 16-bit straight PCM	←	¢
Maximum number of phrases	-	256	1024
Sampling frequency (kHz)	4.0/ 6.4/ 8.0/ 12.8/ 16.0/ 32.0	4.0/ 5.3/ 6.4/ 8.0/ 10.7/ 12.8/ 16.0	4.0/5.3/6.4/8.0/10.6/ 12.0/12.8/16.0/21.3/ 24.0/25.6/32.0/48.0
Clock frequency	4.096MHz (with a built-in crystal oscillator circuit)	←	←
D/A converter	14 bits	$\leftarrow$	16 bits
Low-pass filter	2nd order comb. filter	FIR interpolation filter	$\leftarrow$
Speaker driving amplifier	N.A.	N.A.	Built-in 0.7W (8Ω, DV <sub>DD</sub> = 5 V)
Edit ROM function	Available	$\leftarrow$	$\leftarrow$
Simultaneous sound production function (mixing function)	Monaural	4-channels	←
Volume control	8 levels	29 levels	32 levels
Silence insertion	N.A.	20 ms to 1024 ms (4 ms step)	$\leftarrow$
Repeat function	Available	$\leftarrow$	$\leftarrow$
Silent interval for seam during continuous playback (*1)	No (Seamless)	←	←
Power supply voltage	2.7 V to 5.5 V	<i>~</i>	<i>~</i>
Package	56-pins QFP	80-pins TQFP	30-pins SSOP

The following table shows the differences among the other speech synthesis LSIs.

\*1: Continuous playback as shown below is possible.



#### FEDL22420DIGEST-04

# **OKI SEMICONDUCTOR**

#### ML22420MB/ ML22460MB



# **BLOCK DIAGRAMS**

(ML22460MB : I2C interface)



# (ML22420MB : Synchronous serial interface)

#### PIN CONFIGURATIONS (TOP VIEW)

(ML22420MB : Synchronous serial interface)







### PIN DESCRIPTION (COMMON TO ALL PRODUCTS)

Pin	Symbol	I/O	Initial value (*1)	Description
1	AIN	I	0	Input pin for speaker amplifier.
2	TESTI	I	0	Input pin for testing. Fix this pin to "L" level (DGND level). This pin has a pull-down resistor
3	RESETB	I	0 (*2)	Input pin for reset. At the "L" level, the LSI enters initial state. During reset, the entire circuitry stops and enters power down state. Input "L" level when power is supplied. After the power supply voltage is stable, drive this pin to "H" level. Then the entire circuitry can be powered up. This pin has a pull-up resistor built in.
4,6,7	TESTO (0,1,2)	0	Hi-Z	Output pins for testing. Leave these pins open.
8,14	DGND			Ground pins for logic circuitry.
13	CBUSYB	0	1	Output pin for command processing status. This pin outputs "L" level during command processing. Any command should be entered when this pin is "H" level.
15	ХТ	Ι	0	Connect to the crystal or ceramic resonator. A feedback resistor around 1 $M\Omega$ is built in between this pin and the XTB pin. Use this pin if need to use an external clock. If the resonator is used, connect it as close to this pin as possible.
16	ХТВ	0	1	Connect to the crystal or ceramic resonator. When to use an external clock, leave this pin open. If the resonator is used, connect it as close to this pin as possible.
17, 22	$DV_{DD}$	_	—	Power supply pins for logic circuitry. Connect a capacitor of $0.1 \mu F$ or more between these pins and DGND pins.
18	PSO	0	1	Serial data output pin for voice ROM interface.
19	PSI	I	Hi-Z	Serial data input pin for voice ROM interface.
20,23	N.C.			Non connected pins. Leave these pins open.
21	V <sub>DDL</sub>		_	Regulator output pin for internal logic circuitry. Connect a capacitor recommended between this pin and DGND pin.
24	PSCK	0	1	Clock output pin for voice ROM interface.
25	PCSB	0	1	Chip select output pin for voice ROM interface. At the "L" level, ROM access is available.
26	SG		0	Reference voltage output pin for the speaker amplifier built-in. Connect a capacitor recommended between this pin and DGND pin.
27	SPV <sub>DD</sub>	—		Power supply pin for the speaker amplifier. Connect a bypass capacitor of $0.1\mu F$ or more between this pin and SPGND pin.
28	SPGND	_	_	Ground pin for the speaker amplifier.
29	SPP	0	0	Positive(+) output pin of the speaker amplifier built-in. Serves as the LINE output (*3), if built-in speaker amplifier is not used.
30	SPM	0	Hi-Z	Negative(-) output pin of the speaker amplifier built-in.

\*1: Indicate the initial value during reset input or power down.

\*2: "H" during power down.

\*3: Output a voice signal before amplified by the speaker amplifier built-in.

### PIN DESCRIPTION (FOR ML22420 SYNCHRONOUS SERIAL INTERFACE)

Pin	Symbol	I/O	Initial value	Description
5	DIPH	I	0	Set pin of the SCK clock edge. When this pin is "L" level, rising edge is available for input(SI) and falling edge is available for output(SO). When this pin is "H" level, falling edge is available for input(SI) and rising edge is available for output(SO).
9	CSB	Ι	1	Chip select pin. At the "L" level, data input/output is available.
10	SCK		0	Synchronous clock input pin for serial interface.
11	SI	I	0	Input pin of synchronous serial data. When the DIPH pin is "L" level, data is shifted in at the rising edges of the SCK clock pulses. When the DIPH pin is "H" level, data is shifted in at the falling edges of the SCK clock pulses.
12	SO	0	Hi-Z	Output pin of synchronous serial data. When the DIPH pin is "L" level, data is output at the falling edges of the SCK clock pulses. When the DIPH pin is "H" level, data is output at the rising edges of the SCK clock pulses. When the CSB pin is "H" level, this pin is Hi-Z state.

\*1: Indicate the initial value during reset or power down.

### PIN DESCRIPTION (FOR ML22460 I2C INTERFACE)

Pin	Symbol	I/O	Initial value (*1)	Description
5, 9, 12	SAD0 SAD1 SAD2	I	0	Set pin of the slave address.
10	SCL	I	0	Clock input pin for I2C serial interface. This pin should be connected to pull-up resistor.
11	SDA	Ю	0	Input/output pin for I2C serial data. Use for setting the mode of write/read and writing address, writing data or reading data. This pin should be connected to pull-up resistor. (N-ch MOS) open drain, when output mode. High impedance(Hi-Z), when input mode.

\*1: Indicate the initial value during reset or power down.

## ABSOLUTE MAXIMUM RATINGS

 $(DGND = SPGND = 0 V, Ta = 25^{\circ}C)$ 

Parameter	Symbol	Condition	Rating	Unit
Power supply voltage	$DV_{DD},$ SPV <sub>DD</sub>	_	–0.3 to +7.0	V
Input voltage	V <sub>IN</sub>		-0.3 to DV <sub>DD</sub> +0.3	V
Power dissipation	PD	—	938	mW
		Applies to all pins except SPM, SPP and V <sub>DDL</sub> pins.	10	mA
Output short-circuit current	I <sub>OS</sub>	Applies to SPM and SPP pins.	300	mA
		Applies to V <sub>DDL</sub> pin.	50	mA
Storage temperature	T <sub>STG</sub>	—	–55 to +150	°C

### **RECOMMENDED OPERATING CONDITIONS**

					(DGND	= SPGND = 0 V)
Parameter	Symbol	Condition	Range			Unit
Power supply voltage	$DV_{DD},$ $SPV_{DD}$	_	2.7 to 5.5			V
Operating temperature	T <sub>OP</sub>		-40 to +85			°C
Martin de la francisca	fosc	_	Min.	Тур.	Max.	
Master clock frequency			3.5	4.096	4.5	INILIZ
External capacitors for crystal oscillator	Cd, Cg	—	15	30	45	pF

### **ELECTRICAL CHARACTERISTICS**

### DC Characteristics (for the 3V applications)

	$DV_{DD}$ = SPV <sub>DD</sub> = 2.7 to 3.6 V, DGND = AGND = 0 V, Ta = -40 to +85°C					
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
"H" input voltage	VIH	_	$0.86 \times DV_{DD}$	_	DV <sub>DD</sub>	V
"L" input voltage	VIL		0		$0.14 \times DV_{DD}$	V
"H" output voltage 1	V <sub>OH1</sub>	I <sub>ОН</sub> = –1 mA	DV <sub>DD</sub> -0.4		—	V
"H" output voltage 2 (*1)	V <sub>OH2</sub>	I <sub>OH</sub> = –50 μA	DV <sub>DD</sub> -0.4		—	V
"L" output voltage 1	V <sub>OL1</sub>	I <sub>OL</sub> = 2 mA	—		0.4	V
"L" output voltage 2 (*1)	V <sub>OL2</sub>	I <sub>OL</sub> = 50 μA	—		0.4	V
"L" output voltage 3 (*2)	V <sub>OL3</sub>	I <sub>OL</sub> = 3 mA	—		0.4	V
"H" input current 1	I <sub>IH1</sub>	$V_{IH} = DV_{DD}$	—		10	μA
"H" input current 2 (*3)	I <sub>IH2</sub>	$V_{IH} = DV_{DD}$	0.3	2.0	15	μA
"H" input current 3 (*4)	I <sub>IH3</sub>	$V_{IH} = DV_{DD}$	2	30	200	μA
"L" input current 1	I <sub>IL1</sub>	V <sub>IL</sub> = GND	-10		—	μA
"L" input current 2 (*3)	I <sub>IL2</sub>	V <sub>IL</sub> = GND	-15	-2.0	-0.3	μA
"L" input current 3 (*5)	I <sub>IL3</sub>	V <sub>IL</sub> = GND	-200	-30	-2	μA
"H" output leak current 3	1				10	
(*6)	IILOH	VOH - DVDD			10	μΑ
"L" output leak current 3	lu er		10			
(*6)	ILOL		-10			μΑ
Supply current during	laa	f <sub>OSC</sub> = 4.096 MHz		_	20	mΔ
playback	טטי	No output load			20	
Power-down supply	Inne	Ta = -40 to +40°C		1	10	μA
current	אטטי	Ta = -40 to +85°C		1	20	μA

\*1: Applies to the XTB pin.

\*2: Applies to the SCL and SDA pins.

\*3: Applies to the XT pin.

\*4: Applies to the TESTI pin.

\*5: Applies to the RESETB pin.

\*6: Applies to the TESTO(0, 1 and 2) pins.

		$DV_{DD} = SPV_{DD} = 4.5$ to	5.5 V, DGND	= SPGND = 0	V, Ta = –40 t	o +85°C
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit
"H" input voltage	VIH	—	$0.8 \times DV_{DD}$	_	DV <sub>DD</sub>	V
"L" input voltage	VIL	—	0	_	0.2×DV <sub>DD</sub>	V
"H" output voltage 1	V <sub>OH1</sub>	I <sub>ОН</sub> = –1 mA	DV <sub>DD</sub> -0.4	—	—	V
"H" output voltage 2 (*1)	V <sub>OH2</sub>	I <sub>OH</sub> = –50µА	DV <sub>DD</sub> -0.4	—	—	V
"L" output voltage 1	V <sub>OL1</sub>	I <sub>OL</sub> = 2 mA	—	—	0.4	V
"L" output voltage 2 (*1)	V <sub>OL2</sub>	I <sub>OL</sub> = 50 μA	—	—	0.4	V
"L" output voltage 3 (*2)	V <sub>OL3</sub>	I <sub>OL</sub> = 3 mA	—	_	0.4	V
"H" input current 1	I <sub>IH1</sub>	$V_{IH} = DV_{DD}$	—	—	10	μA
"H" input current 2 (*3)	I <sub>IH2</sub>	$V_{IH} = DV_{DD}$	0.8	5.0	20	μA
"H" input current 3 (*4)	I <sub>IH3</sub>	$V_{IH} = DV_{DD}$	20	100	400	μA
"L" input current 1	I <sub>IL1</sub>	V <sub>IL</sub> = GND	-10	—	—	μA
"L" input current 2 (*3)	I <sub>IL2</sub>	V <sub>IL</sub> = GND	-20	-5.0	-0.8	μA
"L" input current 3 (*5)	I <sub>IL3</sub>	V <sub>IL</sub> = GND	-400	-100	-20	μA
<pre>"L" output leak current 2 (*6)</pre>	I <sub>ILOH</sub>	$V_{OH} = DV_{DD}$	—	—	10	μA
"L" output leak current 3 (*6)	I <sub>ILOL</sub>	V <sub>OL</sub> = GND	-10	—	—	μA
Supply current during playback	I <sub>DD</sub>	f <sub>OSC</sub> = 4.096 MHz No output load	_	_	25	mA
Power-down supply	1000	Ta = -20 to +40°C	—	1	15	μA
current	IDDS	Ta = -20 to +85°C		1	30	μA

### **DC** Characteristics (for the 5V applications)

\*1: Applies to the XTB pin.

\*2: Applies to the SCL and SDA pins.

\*3: Applies to the XT pin.

\*4: Applies to the TESTI pin.

\*5: Applies to the RESETB pin.

\*6: Applies to the TESTO(0, 1 and 2) pins.

$DV_{DD} = SPV_{DD} = 2.7$ to 3.6 V, DGND = SPGND = 0 V, 1a = -40 to +85 C										
Parameter	Symbol	Condition	Min.	Тур.	Max.	Unit				
AIN input resistance	R <sub>AIN</sub>	—	15	20	25	kΩ				
AIN input voltage range	VAIN			_	DV <sub>DD</sub> ×2/3	Vp-p				
LINE output load	Р	During $1/2$ DV output	10			kO				
resistance	RLA	During 1/2 DV <sub>DD</sub> output	10			K52				
LINE output voltage	V	No output load				V				
range	VAO		DVDD/0		DVDD×3/0	v				
SG output voltage	$V_{SG}$	—	$0.95 \times V_{DDL}/2$	$V_{DDL}/2$	1.05×V <sub>DDL</sub> /2	V				
SG output resistance	R <sub>SG</sub>	During power down	57	96	135	kΩ				
SPM, SPP output load	RUSP	_	8	_	_	Ω				
resistance	I LOP	I CLOF					Ŭ			
Speaker amplifier output	D	$SPV_{DD} = 3.3V, f = 1kHz$	100	200		m\\/				
power	⊂ SPO	R <sub>SPO</sub> <b>=</b> 8Ω, THD≥10%	100	300		11177				
Output offset voltage		SPIN SPM gain - OdP								
between SPM and SPP	VOF	With a load of 90	-50	—	+50	mV				
with no signal present		With a 10au 01 022								

#### Characteristics of Analog Circuitry (for the 3V applications) $DV_{DD} = SPV_{DD} = 2.7 \text{ to } 3.6 \text{ V}$ DGND = SPGND = 0.V. Ta = -40 to +85°C

#### Characteristics of Analog Circuitry (for the 5V applications)

	$DV_{DD}$ = $SPV_{DD}$ = 4.5 to 5.5 V, DGND = $SPGND$ = 0 V, Ta = -20 to +					
Parameter Symbol		Condition	Min.	Тур.	Max.	Unit
AIN input resistance	R <sub>AIN</sub>		15	20	25	kΩ
AIN input voltage range	V <sub>AIN</sub>		_		DV <sub>DD</sub> ×2/3	Vp-p
LINE output load R <sub>LA</sub>		During 1/2 DV <sub>DD</sub> output	10	_	—	kΩ
LINE output voltage range	V <sub>AO</sub>	No output load	DV <sub>DD</sub> /6		DV <sub>DD</sub> ×5/6	V
SG output voltage	$V_{SG}$		0.95×V <sub>DDL</sub> /2	V <sub>DDL</sub> /2	1.05×V <sub>DDL</sub> /2	V
SG output resistance	R <sub>SG</sub>	During power down	57	96	135	kΩ
SPM, SPP output load Ri Ri		_	8	_		Ω
Speaker amplifier output power	P <sub>SPO</sub>	$\begin{array}{l} SPV_{DD} = 5.0V, \mbox{ f = 1kHz} \\ R_{SPO} = 8\Omega, \mbox{ THD}{\geq}10\% \\ Ta=25^{\circ}C \end{array}$	500	700		mW
Output offset voltage between SPM and SPP with no signal present	V <sub>OF</sub>	SPIN–SPM gain = 0dB With a load of 8Ω	-50		+50	mV

#### FUNCTIONAL DESCRIPTION

#### Synchronous Serial Command Interface (Applied to ML22420)

The CSB, SCK, SI, and SO pins are used to input the command data or to read the status. Driving the CSB pin to "L" level enables the serial CPU interface.

After the CSB pin is driven to "L" level, the command data are input through the SI pin from the MSB synchronized with the SCK clock. The command data shifts in through the SI pin at the rising or falling edge of the SCK clock pulse. Then, a command is executed at the rising or falling edge of the eighth pulse of the SCK clock.

As for status reading, status is output from the SO pin, synchronized with the SCK clock after the CSB pin is driven to "L" level.

The SCK clock edge is specified by the input level of the DIPH pin.

- When the DIPH pin is "L" level, rising edge is available for input from SI pin and falling edge is available for output from SO pin.
- When the DIPH pin is "H" level, falling edge is available for input from SI pin and rising edge is available for output from SO pin.

It is possible to input command data, even if the CSB pin is fixed by "L" level. However, if unexpected pulses caused by noise are induced through the SCK pin, SCK clock pulses are incorrectly counted, causing a failure in normal recognition of command. Then it is recommended that the CSB pin is "L" level only for command input.

The count of the SCK clock pulse is initialized when the CSB pin goes to "H" level.

Command Data Input or Status Read Timing

• When DIPH pin is "L" level



• When DIPH pin is "H" level



The following table shows the contents of each data output at a status read.

bit	Output status signal
MSB	Channel 4 BUSYB output (BUSYB3)
7SB	Channel 3 BUSYB output (BUSYB2)
6SB	Channel 2 BUSYB output (BUSYB1)
5SB	Channel 1 BUSYB output (BUSYB0)
4SB	Channel 4 NCR output (NCR3)
3SB	Channel 3 NCR output (NCR2)
2SB	Channel 2 NCR output (NCR1)
LSB	Channel 1 NCR output (NCR0)

The BUSYB output is "L" level when a command is being processed or the playback of a particular channel is going on. In other states, the BUSYB output is "H" level. The NCR output is "L" level when a command is being processed or particular channel is in standby for playback. In other states, the NCR output is "H" level.

#### I2C Command Interface (Applied to ML22460)

The I2C Interface built-in is an serial interface (: slave side) that is compliant with I2C bus specification. It supports Fast mode and enables data transmission/reception at 400 kbps. The SCL and SDA pins are used to input the command data or to read the status. Pins (:SAD0, 1 and 2) are used to set the slave address. Pull-up resister should be connected to SCL pin and SDA pin.

For the master on the I2C bus to communicate with this device (: slave), input the slave address with the first seven bits after setting the start condition. The upper three bits of the slave address can be set using the SAD0 to 2 pins. The eighth bit of slave address is used to set the direction (: write or read) of communication. If the eighth bit is "0" level, it is write mode from master to slave. And, if the eighth bit is "1" level, it is read mode from master.

The communication is made in the unit of byte. And acknowledge is needed for each byte.

The protocol of I2C communication is shown below.

- Command flow at the data write Start condition Slave address +W(0) Write address (ex. 1st byte of the command) Write data (ex. 2nd byte of the command) STOP condition
  - Data write timing



- Command flow at the data read Start condition Slave address +R(1) Read data (ex. Status read) STOP condition
  - Data read timing



SAD2	SAD1	SAD0	Lower 4 bits
0	0	0	0101
0	0	1	0101
0	1	0	0101
0	1	1	0101
1	0	0	0101
1	0	1	0101
1	1	0	0101
1	1	1	0101

Setting of the slave address using the SAD0 to 2 pins

The following table shows the contents of each data output at the status read. Status is updated by the RDSTAT command, therefore, be sure to input the RDSTAT command in order to read status.

bit	Output status signal
MSB	Channel 4 BUSYB output (BUSYB3)
7SB	Channel 3 BUSYB output (BUSYB2)
6SB	Channel 2 BUSYB output (BUSYB1)
5SB	Channel 1 BUSYB output (BUSYB0)
4SB	Channel 4 NCR output (NCR3)
3SB	Channel 3 NCR output (NCR2)
2SB	Channel 2 NCR output (NCR1)
LSB	Channel 1 NCR output (NCR0)

The BUSYB signal is "L" level when either a command is being processed or the playback of a particular channel is going on. In other states, the BUSYB signal is "H" level. The NCR signal is "L" level when either a command is being processed or a particular channel is in standby for playback. In other states, the NCR signal is "H" level.

#### **Command List**

Each command is configured by the unit of byte (:8-bits). The following commands, AMODE, AVOL, FADR, PLAY, MUON and CVOL, use two bytes.

Command	D7	D6	D5	D4	D3	D2	D1	D0	Description
PUP	0	0	0	0	0	0	0	0	Power-up command. shift from the power down state to the command waiting state
PDWN	0	0	1	0	0	0	0	0	Power-down command. shift from the command waiting state to the power down state
RDSTAT	1	0	1	1	0	0	0	0	Status read command. Read the command status of each channel.
	0	0	0	0	0	1	0	0	Control command of analog circuitry.
AMODE	FAD	DAG1	DAG0	AIG1	AIG0	DAEN	SPEN	POP	and input/output.
PLAY	0	1	0	0	F9	F8	C1	C0	Playback start command. Set phrase address using F9 to F0
,	F7	F6	F5	F4	F3	F2	F1	F0	bits for each channel. Set channel using C1 and C0 bits.
STOP	0	1	1	0	СНЗ	CH2	CH1	CH0	Playback stop command. Can be set for each channel.
	0	0	1	1	F9	F8	C1	C0	Set command of playback phrase.
FADR	F7	F6	F5	F4	F3	F2	F1	F0	Can be set for each channel. Use START command to start.
START	0	1	0	1	СНЗ	CH2	CH1	СНО	Playback start command without phrase spec. Use FADR command to set phrase. Can start playback on multiple channels simultaneously. After played back by PLAY command, the same phrase can be played back with this command.
MUON	0	1	1	1	СНЗ	CH2	CH1	CH0	Silence insertion command. Set the silent time length for each
MOON	M7	M6	M5	M4	М3	M2	M1	M0	channel using M7 to M0 bits in the 2nd byte.
SLOOP	1	0	0	0	СНЗ	CH2	CH1	CH0	Set command of repeat playback. Setting is enabled during playback. Can be specified for each channel.
CLOOP	1	0	0	1	СНЗ	CH2	CH1	CH0	Stop command of repeat playback. Can be specified for each channel. Also, repeat playback is released by STOP command automatically.
	1	0	1	0	СНЗ	CH2	CH1	CH0	Volume control command.
CVUL	0	0	0	CV4	CV3	CV2	CV1	CV0	CV4 to CV0 bits in the 2nd byte.
	0	0	0	0	1	0	0	0	Analog volume control command.
AVOL	0	0	AV5	AV4	AV3	AV2	AV1	AV0	using AV5 to AV0 bits.

#### Voice Synthesis Algorithm

Four types of voice synthesis algorithm are supported. They are OKI 4-bit ADPCM2, OKI 8-bit non-linear PCM, 8-bit straight PCM and 16-bit straight PCM. Select the best one according to the characteristics of playback voice.

The following table shows key features of each algorithm.

Voice synthesis algorithm	Applied waveform	Feature
OKI 4-bit ADPCM2	Normal voice waveform	Up version of OKI's specific voice synthesis algorithm (:OKI 4-bit ADPCM). Voice quality is improved.
OKI 8-bit Nonlinear PCM	Waveform including high frequency signals	Algorithm which plays back mid-range of waveform as 10-bit equivalent voice quality.
8-bit straight PCM		Normal 8-bit PCM algorithm.
16-bit straight PCM	(Sound effect, etc.)	Normal 16-bit PCM algorithm,

#### Memory Allocation and Creating Voice Data

The ROM is partitioned into four data areas: voice (i.e., phrase) control area, test area, voice area, and edit ROM area.

The voice control area manages the voice data in the ROM. It contains data for controlling the start/stop addresses of voice data for 1,024 phrases, use/non-use of the edit ROM function and so on.

The test area contains data for testing.

The voice area contains actual waveform data.

The edit ROM area contains data for effective use of voice data. For the details, refer to the section of "Edit ROM Function."

The edit ROM area is not available if the edit ROM is not used.

The ROM data is created using a dedicated tool.

#### Configuration of ROM data

0x00000 0x01FFF	Voice control area (Fixed 64 Kbits)
0x02000	Test area
0x0205F	
0x02060	Voice area
	Edit ROM area
may: OvEEEEE	Depends on creation of ROM data.

#### **Playback Time and Memory Capacity**

The playback time depends on the memory capacity, sampling frequency, and playback method. The equation to know the playback time is shown below. But this is not applied if the edit ROM function is used.

Playback time [sec] = (Memory capacity – 64) [Kbit] x 1.024 Sampling frequency [kHz] × Bit length

(Bit length is 4 at the 4-bit ADPCM2 and 8/16 at the PCM.)

Example) In the case that the sampling frequency is 16 kHz, algorithm is 4-bit ADPCM2 and ROM capacity is 16 Mbits, the playback time is approx. 261 seconds, as shown below.

Playback time =  $\frac{(16,000 \times 1.024 - 64) \times 1.024}{16 \times 4} \cong 261$  [sec]

#### **Edit ROM Function**

The edit ROM function makes it possible to play back multiple phrases in succession. The following functions are set using the edit ROM function:

Continuous playback: There is no limit to set the number of times of continuous playback. It depends on the memory capacity only.
 Silence insertion: 20ms to 1,024 ms

It is possible to use voice ROM effectively to use the edit ROM function. Below is an example of the ROM structure, case of using the edit ROM function.

Phrase 1	A	D			
Phrase 2	A C	D			
Phrase 3	ЕХВХ	D			
Phrase 4	E C	D			
Phrase 5	А	D Silence	E	С	D



Example 2) Structure of the ROM that contents of example 1 are stored



#### **Mixing Function**

It is possible to perform mixing of four channels simultaneously. And also, it is possible to specify PLAY, STOP, and CVOL commands for each channel respectively. The mixing function is available if the sampling frequency ( $F_s$ ) is 16 kHz or less.

- Precautions for Waveform Clamp

Adjust the volume of each channel using the CVOL command, if the waveform clamp is increased by channel mixing.

### APPLICATION CIRCUIT ML22420: DV<sub>DD</sub>=SPV<sub>DD</sub>=Vdd



# ML22460: $DV_{DD}$ =SPV<sub>DD</sub>= Vdd



### PACKAGE DIMENSIONS



Notes for Mounting the Surface Mount Type Package:

The surface mount type packages are very susceptible to heat in reflow mounting and humidity absorbed in storage. Therefore, before you perform reflow mounting, contact OKI's responsible sales person for the product name, package name, pin number, package code and desired mounting conditions (reflow method, temperature and times).

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